Receipt date: 02/27/2009 10580669 - GAU: 2814

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FORM PTO-1449 INFORMATION DISCLOSURE STATEMENT				ATTY DOCKET NO.	SERIAL NO.			
				536-009.027 To be assigned				
				APPLICANT: Holger RUCKER et al.				
				FILING DATE:	ART UNIT:			
				Herewith	To be assigned			
UNITED STATES PATENT DOCUMENTS								
EXAM. INITIAL		DOCUMENT NUMBER	DATE	INVENTOR/ASSIGNEE	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
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		H.J. Osten et al., <i>The Effect of Carbon Incorporation on SiGe Heterobipolar Transistor Performance and Process Margin</i> ; IEEE 1997 0-7803-4100 (pages 32.4.1 - 32.4.4).						
Examiner (To be assigned) /Long Pham/				Date: 10/23/2009				